## NSN 5961-01-281-4321

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-281-4321 **Inclosure Material:** Ceramic **Overall Length:** 0.770 inches **Terminal Length:** 0.230 inches **Overall Height:** 0.120 inches **Overall Width:** 0.310 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Mo-036ab **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -200.0 drain to gate voltage all transistor and -200.0 drain to source voltage all transistor and -20.0 gate to source voltage all transistor **Current Rating Per Characteristic:** -1.60 amperes off-state current, peak all transistor **Power Rating Per Characteristic:** 1.4 watts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No